



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} | I _D T _A = +25°C |
|----------------------|---------------------------------|------------------------------------------|
| 24V | 15mΩ @ V_{GS} = 4.5 V | 6.5A |
| 24 V | $20m\Omega$ @ V_{GS} = $2.5V$ | 5.6A |

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

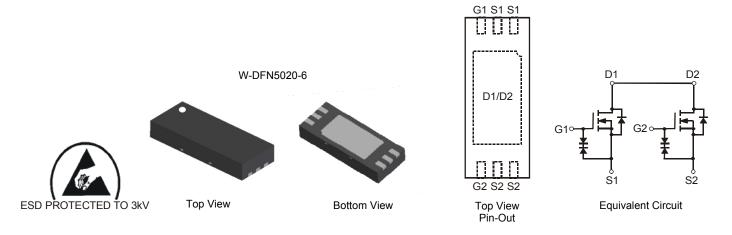
- DC-DC Converters
- Power management functions

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 3kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: W-DFN5020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.03 grams (approximate)



Ordering Information (Note 4)

| 1 | | |
|--------------|-------------|--------------------|
| Part Number | Case | Packaging |
| DMG5802LFX-7 | W-DFN5020-6 | 3000 / Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ME = Product Type Marking Code YM = Date Code Marking

Y = Year (ex: X = 2010)

M = Month (ex: 9 = September)

Date Code Key

| Year | 2010 | 20 | 11 | 2012 | 2013 | 20 | 14 | 2015 | 2016 | 20 | 17 | 2018 |
|-------|------|-----|-----|------|------|-----|-----|------|------|-----|-----|------|
| Code | X | ` | 1 | Z | Α | | В | С | D | I | | F |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteri | Symbol | Value | Unit | | |
|----------------------------------------------------------|-----------------|--------------------------------------------------|------|------------|---|
| Drain-Source Voltage | V_{DSS} | 24 | V | | |
| Gate-Source Voltage | V_{GSS} | ±12 | V | | |
| Continuous Drain Current (Note 5) V _{GS} = 4.5V | Steady State | T _A = +25°C T _A = +70°C | ID | 6.5 5.2 | Α |
| Continuous Drain Current (Note 5) V _{GS} = 2.5V | I _D | 5.6 4.5 | Α | | |
| Pulsed Drain Current (Note 6) | I _{DM} | 70 | Α | | |

Thermal Characteristics

| Characteristic | Symbol | Max | Unit |
|--------------------------------------------------------------------------|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P_{D} | 0.98 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5) | $R_{\theta JA}$ | 126.5 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

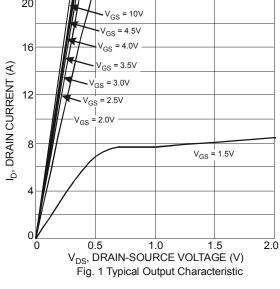
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------------------------------------------|----------------------|-----|--------|-----|-------|-------------------------------------------------|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 24 | _ | _ | V | $V_{GS} = 0V, I_D = 250\mu A$ |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | | _ | 1.0 | μA | $V_{DS} = 24V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | - | _ | ±10 | μΑ | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.6 | 0.9 | 1.5 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ |
| | | _ | 11 | 15 | | $V_{GS} = 4.5V, I_D = 6.5A$ |
| Static Drain-Source On-Resistance | _ | _ | 12 | 17 | mΩ | $V_{GS} = 4V, I_D = 5.6A$ |
| Static Drain-Source On-Resistance | R _{DS (ON)} | _ | 13 | 18 | 11177 | V _{GS} = 3.1V, I _D = 5.6A |
| | | _ | 14 | 20 | | $V_{GS} = 2.5V, I_D = 5.6A$ |
| Forward Transfer Admittance | Y _{fs} | _ | 17 | _ | S | $V_{DS} = 5V, I_{D} = 6.5A$ |
| Diode Forward Voltage | V _{SD} | _ | 0.6 | 0.9 | V | $V_{GS} = 0V, I_{S} = 1A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | _ | 1066.4 | _ | | 151/1/ 01/ |
| Output Capacitance | Coss | _ | 132.0 | _ | pF | $V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | _ | 127.1 | _ | | 1 - 1:01/11/12 |
| Gate Resistance | R_g | - | 1.47 | | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ |
| Total Gate Charge V _{GS} = 4.5V | Qg | _ | 14.5 | _ | | $V_{GS} = 4.5V$, $V_{DS} = 15V$, $I_D = 5.8A$ |
| Total Gate Charge V _{GS} = 10V | Qg | _ | 31.3 | _ | nC | \\ 40\\\\\ 45\\\ |
| Gate-Source Charge | Qgs | _ | 2.0 | _ | IIC | $V_{GS} = 10V, V_{DS} = 15V,$ |
| Gate-Drain Charge | Q _{gd} | _ | 3.1 | | | $I_D = 5.8A$ |
| Turn-On Delay Time | t _{D(on)} | _ | 3.69 | _ | ns | |
| Turn-On Rise Time | t _r | | 13.43 | | ns | V _{GS} = 10V, V _{DS} = 15V, |
| Turn-Off Delay Time | t _{D(off)} | | 32.18 | | ns | $R_L = 2.1\Omega$, $R_G = 3\Omega$ |
| Turn-Off Fall Time | t _f | _ | 22.45 | _ | ns |] |

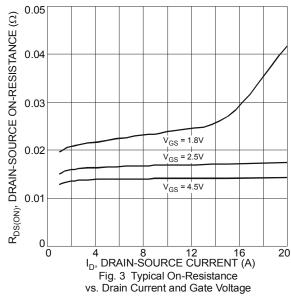
Notes:

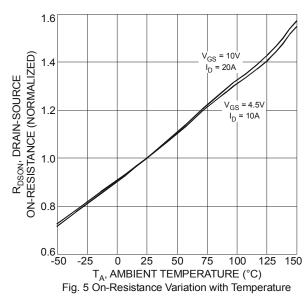
- 5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.6. Repetitive rating, pulse width limited by junction temperature.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

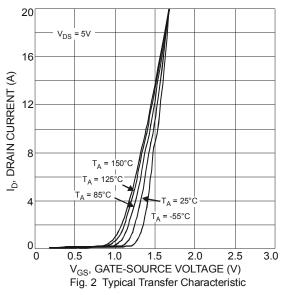


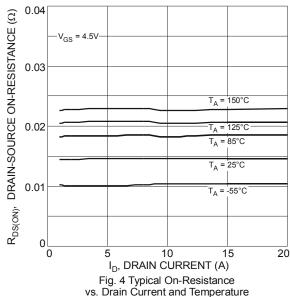












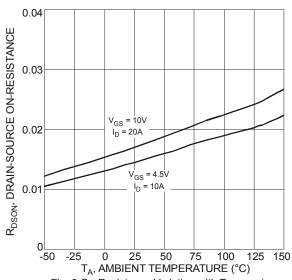
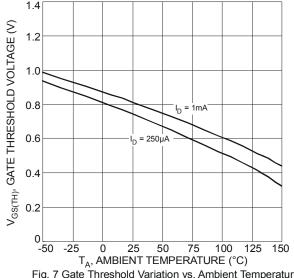


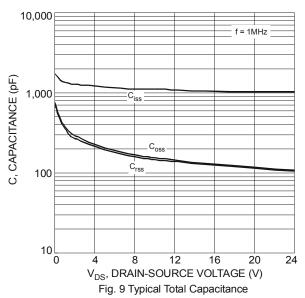
Fig. 6 On-Resistance Variation with Temperature

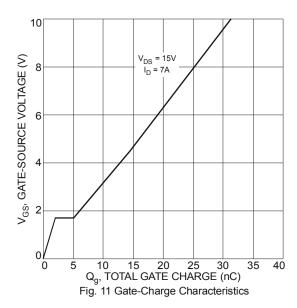


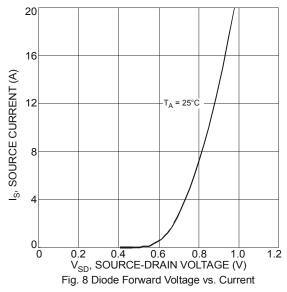


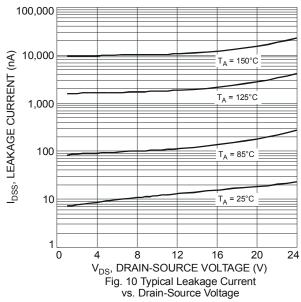


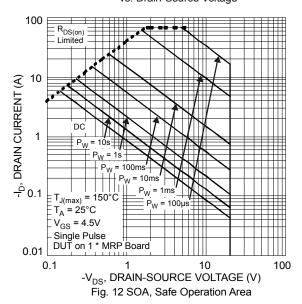




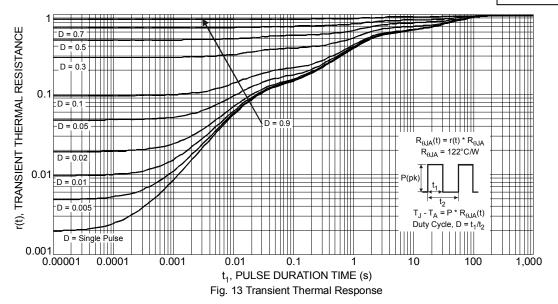






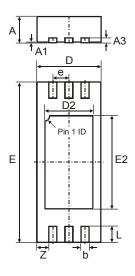






Package Outline Dimensions

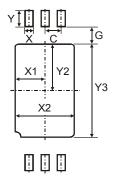
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| W-DFN5020-6 | | | | | | | |
|----------------------|------|------|-------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.75 | 0.85 | 0.80 | | | | |
| A1 | 0 | 0.05 | 0.02 | | | | |
| А3 | _ | - | 0.15 | | | | |
| b | 0.20 | 0.30 | 0.25 | | | | |
| D | 1.90 | 2.10 | 2.00 | | | | |
| D2 | 1.40 | 1.60 | 1.50 | | | | |
| е | _ | _ | 0.50 | | | | |
| Е | 4.90 | 5.10 | 5.00 | | | | |
| E2 | 2.80 | 3.00 | 2.90 | | | | |
| L | 0.35 | 0.65 | 0.50 | | | | |
| Z | _ | _ | 0.375 | | | | |
| All Dimensions in mm | | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.50 |
| G | 0.35 |
| Х | 0.35 |
| X1 | 0.90 |
| X2 | 1.80 |
| Υ | 0.70 |
| Y2 | 1.60 |
| Y3 | 3.20 |



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